







Dual-Wavelength Spectral Purity Filter for EUV Collector Mirrors

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- Introduction
- Spectral Purity Filter for main pulse CO₂ laser wavelength: 10.6 μm
- Spectral Purity Filter for pre pulse YAG laser wavelength: 1064 μm
- Dual-wavelength Spectral Purity Filter
- Summary and acknowledgement



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optiX fab introduction

- Mission: Fabrication of customized EUV optics and optical components for EUV lithography @ 13.5 nm and beyond, synchrotron and FEL beamlines, metrology, R&D applications, etc.
- Foundation: December 17, 2012, fully operational: August 1, 2013
- Address: optiX fab GmbH
 Hans-Knöll-Str. 6
 D 07745 Jena
- Email: info@optixfab.com
- Production: Delivery of > 3000 EUV multilayer mirrors since Aug 1, 2013
- Team:



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Multilayer coated collector optics for LPP sources



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Theoretical reflectance of Mo/Si multilayer for normal incidence



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EUV LPP collector with dual-wavelength spectral purity filter



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Dual-wavelength spectral purity filter – proof of principle

- Realization of binary phase gratings on 6 inch Si wafers
- Optimization of grating and coating for AOI = 15 degrees
- Characterization of grating structure by WLI
- Characterization of grating roughness by AFM
- Characterization of optical properties:
 - EUV reflectance at 13.5 nm and
 - IR suppression at 10.6 μm and 1064 nm



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Spectral Purity Filter for CO_2 laser wavelength: 10.6 μ m





Photographs of grating structure



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White light interferometry of grating structure



Groove depth



2740 nm

Atomic Force Microscopy of grating bar and groove



ox-0026_nw-05radius_graben_io11..102

rms= 0,13 nm; f13 ox-0026_nw-05radius_steg_io21..105

rms roughness on grating groove: σ_{RMS} = 0.15 nm

rms roughness on grating bar: σ_{RMS} = 0.15 nm

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EUV reflectance measurement @ PTB Berlin



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Spectral Purity Filter for YAG laser wavelength: 1064 nm





White light interferometry of grating structure



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Atomic Force Microscopy of grating bar and groove



rms = 0,22 nm; f13 ox-0017_1cmrand-nw_graben_io11..100 rms= 0,22 nm (0,14 nm); fl3 ox-0017_1cmrand-nw_steg_io11..100

rms roughness on grating groove: σ_{RMS} = 0.22 nm

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rms roughness on grating bar:

 $\sigma_{\rm RMS}$ = 0.14 nm

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Dual-wavelength Spectral Purity Filter





White light interferometry of grating structure





Atomic Force Microscopy of grating bar and groove



rms = 0.22 nm, F13 ox-0022-mitte-so-graben-graben_io11.100t

rms = 0.15 nm, F13 ox-0022-mitte-so-graben-steg_io11.105t

rms roughness on grating groove: σ_{RMS} = 0.22 nm

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rms roughness on grating groove:

 $\sigma_{\rm RMS}$ = 0.15 nm

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Atomic Force Microscopy of grating bar and groove



 $\label{eq:rms} \begin{array}{l} \mathsf{rms} = 0.21 \ (0.19) \ \mathsf{nm}, \ \mathsf{Fl3} \\ \mathsf{ox-0022-mitte-so-steg-graben_iol1.101t} \end{array}$

rms = 0.19 (0.18) nm, F13 ox-0022-mitte-so-steg-steg_io11.104t

rms roughness on grating bar: $\sigma_{\rm RMS}$ = 0.19 nm

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rms roughness on grating bar:

 $\sigma_{\rm RMS}$ = 0.18 nm

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Grating efficiency @ 10.6 µm





Grating efficiency @ 1064 nm





Dual grating efficiency @ 10.6 μ m and 1064 nm





Scanning Electron Microscopy of dual-wavelength SPF



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Demonstration of dual-wavelength Spectral Purity Filter concept on 6" Si wafers

EUV reflectance of 10.6 µm grating structure:	67.0 %	(2.0 % loss)
EUV reflectance of 1064 nm grating structure:	66.6 %	(2.4 % loss)
EUV reflectance of dual-wavelength grating:	64.6 %	(4.5 % loss)
0 th order grating efficiency of 10.6 μm grating: 0 th order grating efficiency of 1064 nm grating:	0.06 % 0 17 %	(1500x suppression)
o order grading enterency of 1004 min grading.	0.17 /0	
O th order efficiency of dual wavelength grating:	0.22 %	(450x suppression)
O th order efficiency of dual wavelength grating:	0.22 %	(450x suppression)

next step: technology extension to curved sub-aperture EUV collectors



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EUV grating team @ Fraunhofer IOF:

Christoph Damm, Wilko Fuhlrott, Andreas Gebhardt, Mathias Hauptvogel, Tobias Herffurth, Nils Heidler, Robert Jende, Jan Kinast, Roman Loose, Sandra Müller, Thomas Müller, Michael Scheler, Thomas Peschel, Stefan Risse, Mathias Rohde, Steffen Schulze, Ronald Schmidt, Uta Schmidt, Mark Schürmann, Ralf Steinkopf, Sergiy Yulin

EUV reflectivity measurement team @ PTB Berlin

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